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With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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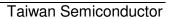
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200mW, PNP Small Signal Transistor

FEATURES

- Epitaxial planar die construction
- Surface mount device type
- Moisture sensitivity level 1
- Matte Tin(Sn) lead finish with Nickel(Ni) underplate
- Pb free and RoHS complian
- Green compound (Halogen free) with suffix "G" on packing code and prefix "G" on date code

MECHANICAL DATA

- Case: SOT- 323 small outline plastic package
- Terminal: Matte tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- High temperature soldering guaranteed: 260°C/10s
- Weight: 0.005 grams (approximately)









SOT-323

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)					
PARAMETER	SYMBOL	VALUE	UNIT		
Power Dissipation	P _D	200	mW		
Collector-Base Voltage	V _{CBO}	50	V		
Collector-Emitter Voltage	V _{CEO}	45	V		
Emitter-Base Voltage	V _{EBO}	5	V		
Collector Current	I _C	0.5	Α		
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	625	K/W		
Junction and Storage Temperature Range	T_J,T_STG	-55 to + 150	°C		

Notes: 1. Transistor mounted on a FR4 printed-circuit board

PARAMI	SYMBOL	MIN	MAX	UNIT	
Collector-Base Breakdown Voltage	at -I _C = 10 μA	V _{(BR)CBO}	50	=	V
Collector-Emitter Breakdown Voltage	at -I _C = 10 mA	V _{(BR)CEO}	45	-	V
Emitter-Base Breakdown Voltage	at -I _E = 10 μA	$V_{(BR)EBO}$	5	-	V
Callantar Cut off Current	at V _{CB} = 20 V	1	-	100	nA
Collector Cut-off Current	at V_{CB} = 20 V , T_J = 150 $^{\circ}$ C	I _{CBO}		5	μΑ
Emitter Cut-off Current	at V _{EB} = 5 V	I _{EBO}	-	100	nA
Collector-Emitter Saturation Voltage	at - $I_C = 500$ mA $I_B = 50$ m	A V _{CE(sat)}	-	0.7	V
Transition Frequency	$V_{CE} = 5 \text{ V} \text{ I}_{C} = 10 \text{ mA f} = 100 \text{MH}$	lz f _⊤	80	-	MHz
at -V _{CE} = 1 '	V , -I _C = 100 mA				
	-16W		100	250	
DC Current Gain	-25W	h _{FE}	160	400	
	-40W		250	600	
at $-V_{CF} = 1 \text{ V}$, $-I_{C} = 500 \text{ mA}$			40		



RATINGS AND CHARACTERISTICS CURVES

40

60

80

T_S (°C)

100

(TA=25°C unless otherwise noted)

300

250

200

150

100

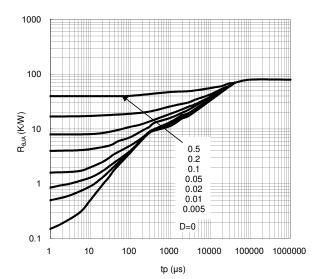
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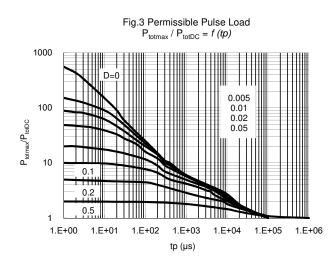
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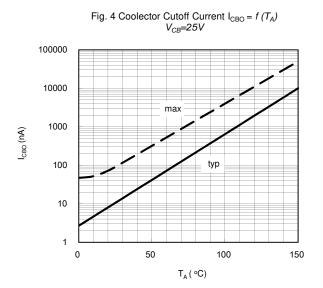
P_{tot} (mW)

Fig.1Total Power Dissipation $P_{tot} = f(T_S)$

Fig.2 Permissible Pulse Load $R_{\theta JA} = f(tp)$



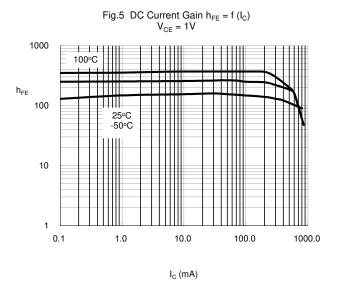


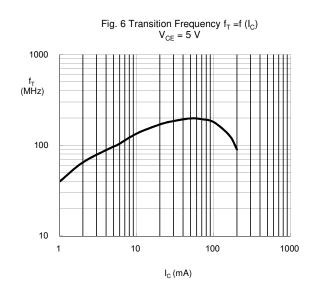


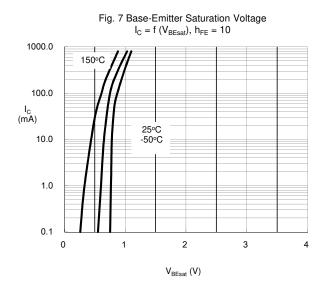


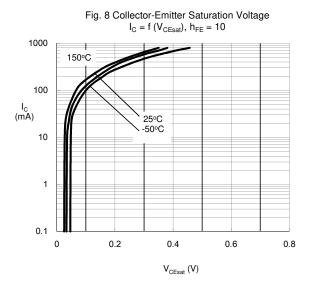
RATINGS AND CHARACTERISTICS CURVES

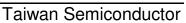
(TA=25°C unless otherwise noted)











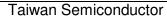


ORDERING INFORMATION						
PART NO.	MANUFACTURE CODE	PACKING CODE	GREEN COMPOUND CODE	PACKAGE	PACKING	MARKING
BC807-16W	(Note)	RF	G	SOT-323	3K / 7" Reel	5CR
BC807-25W		RF	G	SOT-323	3K / 7" Reel	5CS
BC807-40W		RF	G	SOT-323	3K / 7" Reel	5CT

Note: Manufacture special control, if empty means no special control requirement.

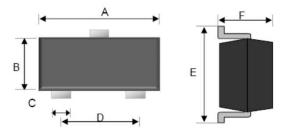
EXAMPLE					
PREFERRED P/N	PART NO.	MANUFACTURE CODE	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION
BC807-16W RFG	BC807-16W		RF	G	Green compound
BC807-16W-B0 RFG	BC807-16W	B0	RF	G	Green compound

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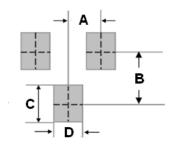


DIMENSIONS

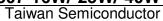


11.1/4					
DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	1.80	2.20	0.07	0.09	
В	1.15	1.35	0.05	0.05	
С	0.15	0.40	0.01	0.02	
D	1.20	1.40	0.05	0.06	
E	2.00	2.45	0.08	0.10	
F	0.80	1.10	0.03	0.04	

SUGGEST PAD LAYOUT



DIM.	Unit(mm)	Unit(inch)
DIIVI.	Тур.	Тур.
Α	0.65	0.026
В	1.6	0.063
С	0.8	0.031
D	0.8	0.031





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